

1. General description

Dual Silicon Carbide Schottky diode in a 3-lead TO-247 plastic package, designed for high frequency switched-mode power supplies.

2. Features and benefits

- Highly stable switching performance
- High forward surge capability IFSM
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

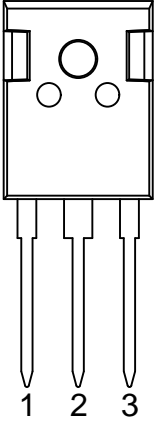
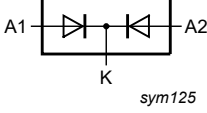
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	650	V
$I_{O(AV)}$	limiting average output current	$T_{mb} \leq 43\text{ °C}$; $\delta_{factor} = 0.5$; square-wave pulse; both diodes conducting; Fig. 1 ; Fig. 2 ; Fig. 3 ; Fig. 4	-	-	30	A
T_j	junction temperature		-	-	175	°C
Static characteristics						
V_F	forward voltage	$I_F = 15\text{ A}$; $T_j = 25\text{ °C}$; Fig. 6	-	1.75	1.95	V
		$I_F = 15\text{ A}$; $T_j = 150\text{ °C}$; Fig. 6	-	2.4	2.8	V
Dynamic characteristics						

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Q_r	recovered charge	$I_F = 15\text{ A}$; $di_F/dt = 500\text{ A}/\mu\text{s}$; $V_R = 400\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 7	-	15	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode	 <p style="text-align: center;">TO-247 (SOT429N)</p>	 <p style="text-align: center;"><i>sym125</i></p>
2	K	cathode		
3	A2	anode		
mb	mb	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NXPLQSC30650W	TO-247	Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3-lead TO-247	SOT429N

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	650	V
V_{RWM}	crest working reverse voltage		-	650	V
V_R	reverse voltage	DC	-	650	V
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25 \mu s$; $T_{mb} \leq 56 \text{ }^\circ\text{C}$; square-wave pulse; per diode	-	30	A
$I_{O(AV)}$	limiting average output current	$T_{mb} \leq 43 \text{ }^\circ\text{C}$; $\delta_{factor} = 0.5$; square-wave pulse; both diodes conducting; Fig. 1 ; Fig. 2 ; Fig. 3 ; Fig. 4	-	30	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8.3 \text{ ms}$; $T_{j(init)} = 25 \text{ }^\circ\text{C}$; sine-wave pulse; per diode	-	55	A
		$t_p = 10 \mu s$; $T_{j(init)} = 25 \text{ }^\circ\text{C}$; square-wave pulse; per diode	-	450	A
T_{stg}	storage temperature		-55	175	$^\circ\text{C}$
T_j	junction temperature		-	175	$^\circ\text{C}$

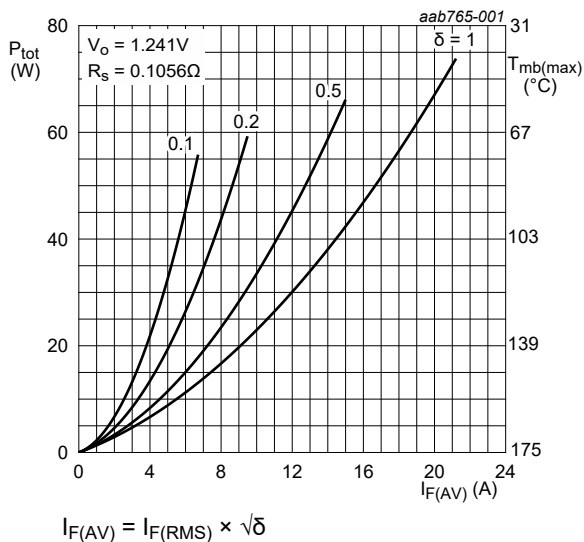


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; per diode

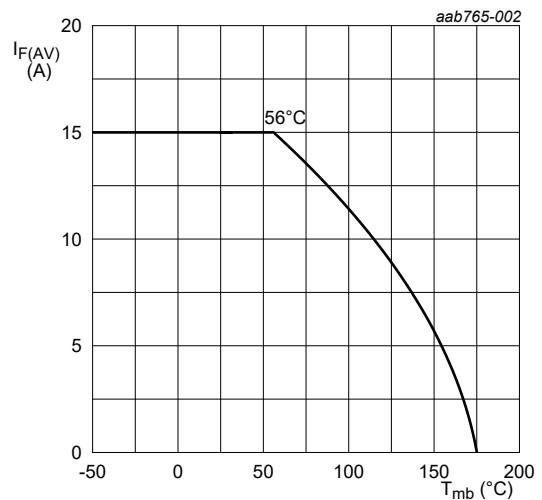


Fig. 2. Forward current as a function of mounting base temperature; per diode

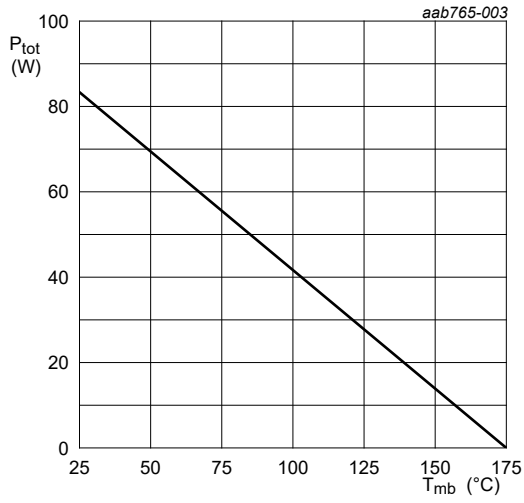


Fig. 3. Total power dissipation as a function of mounting base temperature; per diode

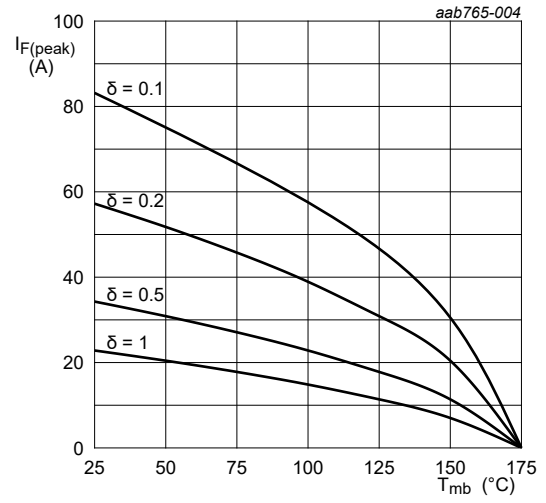


Fig. 4. Current derating as a function of mounting base temperature; per diode

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	per diode; Fig. 5	-	-	1.8	K/W
		both diodes conducting	-	-	1	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W

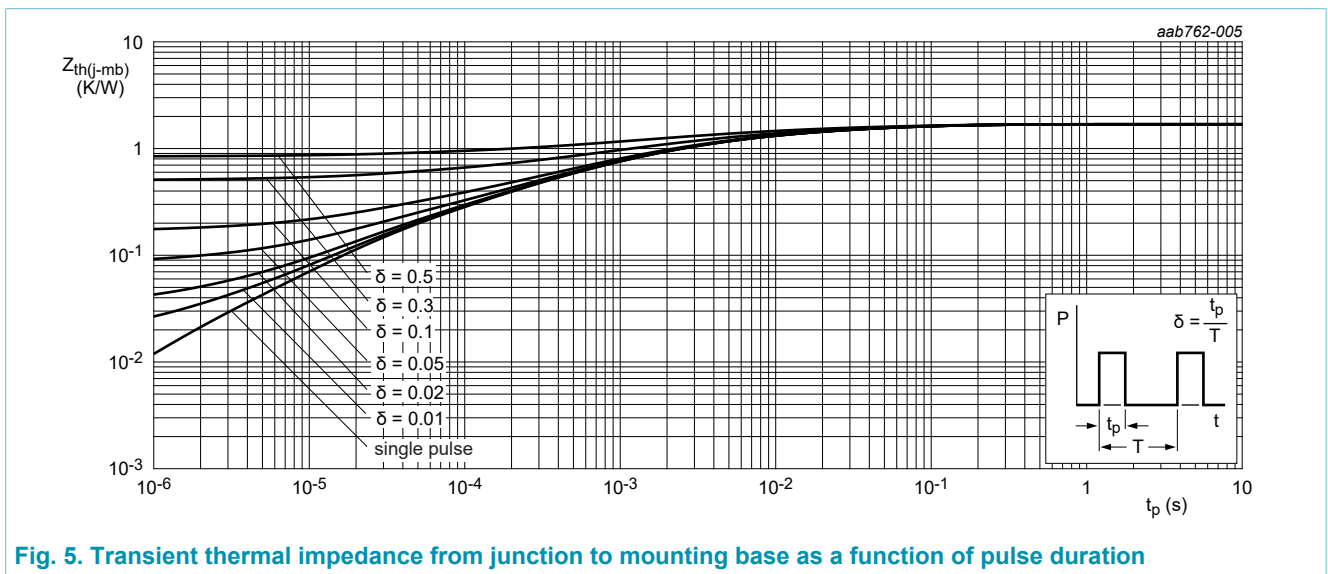


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward voltage	$I_F = 15 \text{ A}; T_j = 25 \text{ }^\circ\text{C}; \text{ Fig. 6}$	-	1.75	1.95	V
		$I_F = 15 \text{ A}; T_j = 150 \text{ }^\circ\text{C}; \text{ Fig. 6}$	-	2.4	2.8	V
I_R	reverse current	$V_R = 650 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$	-	-	250	μA
		$V_R = 650 \text{ V}; T_j = 150 \text{ }^\circ\text{C}$	-	-	800	μA
Dynamic characteristics						
Q_r	recovered charge	$I_F = 15 \text{ A}; dI_F/dt = 500 \text{ A}/\mu\text{s}; V_R = 400 \text{ V}; T_j = 25 \text{ }^\circ\text{C}; \text{ Fig. 7}$	-	15	-	nC
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 1 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$	-	300	-	pF
		$f = 1 \text{ MHz}; V_R = 300 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$	-	32	-	pF
		$f = 1 \text{ MHz}; V_R = 600 \text{ V}; T_j = 25 \text{ }^\circ\text{C}$	-	25	-	pF

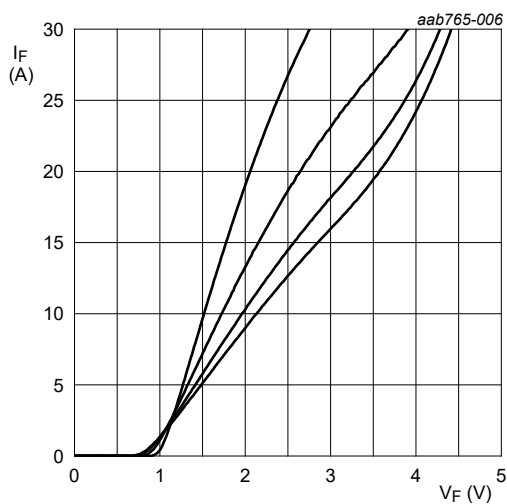


Fig. 6. Forward current as a function of forward voltage; typical values; per diode

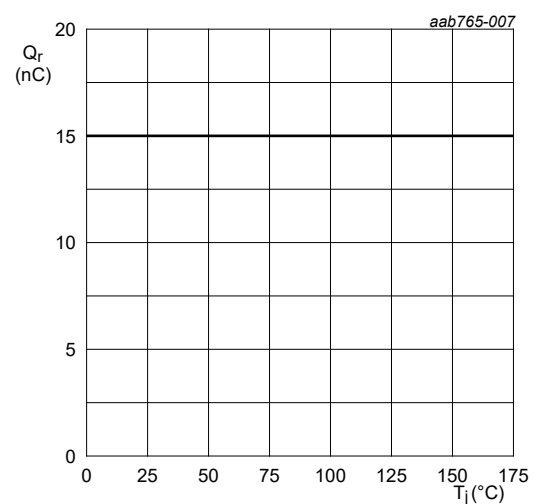


Fig. 7. Recovered charge as a function of junction temperature; per diode

10. Package outline

Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3-lead TO-247

SOT429N

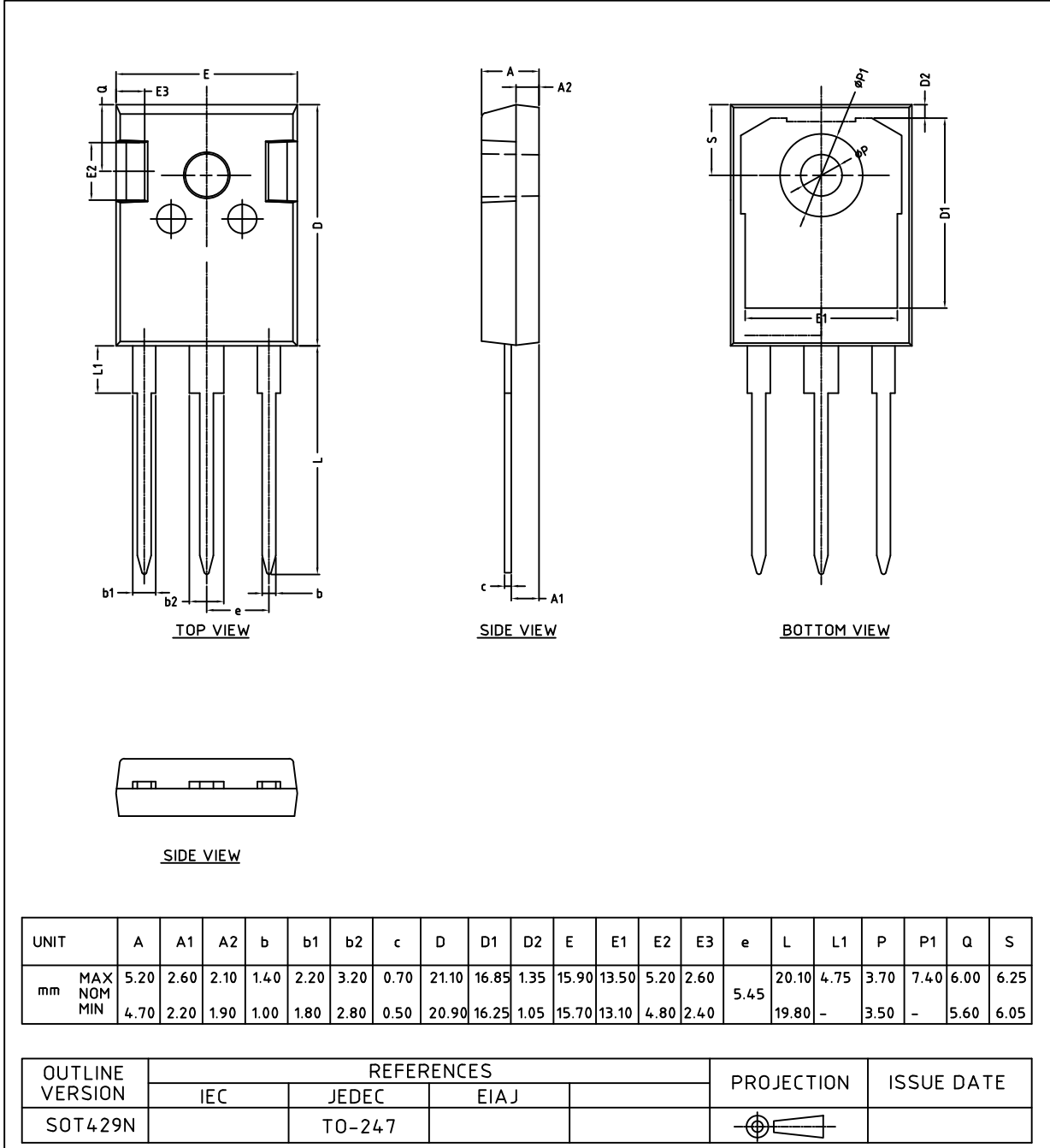


Fig. 8. Package outline TO-247 (SOT429N)

11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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